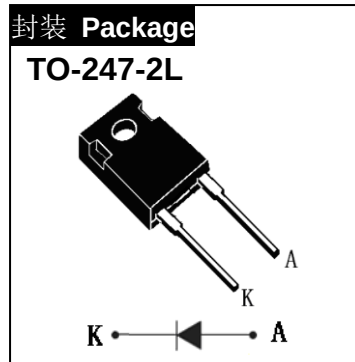




FP60U120BA

主要参数 MAIN CHARACTERISTICS

$I_F(AV)$	60A
V_{RRM}	1200V
$V_F(typ)$	2.90V
$T_{rr}(typ)$	32ns



用途

- 吸收回路
- 开关电源
- UPS
- 高频开关器件并联二极管

APPLICATIONS

- Snubber diode
- Switch power supply
- UPS
- Antiparalle Diode for high frequency switching devices

产品特性

- 超快恢复时间
- 低恢复损耗
- 低正向压降
- 低漏电流

FEATURES

- Ultrafast Recovery Time
- Low Recovery Loss
- Low Forward Voltage
- Low Leakage Current

订货信息 ORDER MESSAGE

订 货 型 号 Order codes		印 记 Marking	封 装 Package
有卤-条管 Halogen-Tube	无卤-条管 Halogen Free-Tube		
FP60U120BA-GL-B	FP60U120BA-GL-BR	FP60U120BA	TO-247-2L





绝对最大额定值 ABSOLUTE RATINGS (Tc=25℃)

项 目 Parameter	符 号 Symbol	数 值 Value	单 位 Unit
反向重复峰值电压 Peak Repetitive Reverse Voltage	V_{RRM}	1200	V
平均正向整流电流 T _C =100℃ Average Forward Rectified Current	$I_{F(AV)}$	60	A
非重复浪涌正向电流 Non-Repetitive Surge Forward Current t=8.3ms	I_{FSM}	590	A
结温 Junction Temperature	T _j	-55~+175	℃
存储温度 Storage temperature range	T _{STG}	-55~+175	℃

电特性 ELECTRICAL CHARACTERISTICS (Tc=25℃ unless otherwise specified)

项 目 Parameter	测试条件 Tests conditions		最小值 Value(min)	典型值 Value(typ)	最大值 Value(max)	单位 Unit
V _R	I _R =50μA		1200	-	-	V
I _R	T _j =25℃	V _R =V _{RRM}	-	-	100	μA
	T _j =150℃		-	-	450	μA
V _F	T _j =25℃	I _F =60A	-	2.90	3.50	V
	T _j =150℃		-		2.80	V
T _{rr}	I _F =1A, V _R =30V, di _F /dt=-200A/μs		-	32	47	ns
T _{rr}	I _F =60A, V _R =600V, di _F /dt=-200A/μs T _C =25℃		-	330	-	ns
Q _{rr}			-	625	-	nc
I _{RRM}			-	5.7	-	A
T _{rr}	I _F =60A, V _R =600V, di _F /dt=-200A/μs T _C =125℃		-	445	-	ns
Q _{rr}			-	2090	-	nc
I _{RRM}			-	11.6	-	A

热特性 THERMAL CHARACTERISTICS (maximum)

项 目 Parameter	符 号 Symbol	最大值 Value(max)	单 位 Unit
结到管壳的热阻 Thermal Resistance Junction to Case	R _{th(j-c)}	0.40	℃/W





特征曲线 ELECTRICAL CHARACTERISTICS (curves)

Fig.1 Typical Forward Characteristics

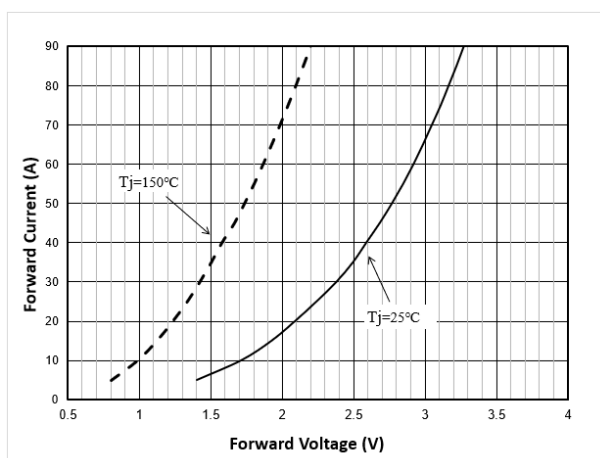


Fig.2 Typical Reverse Characteristics

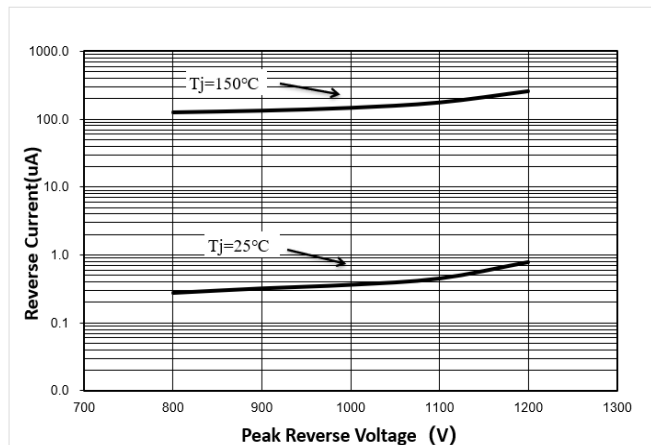
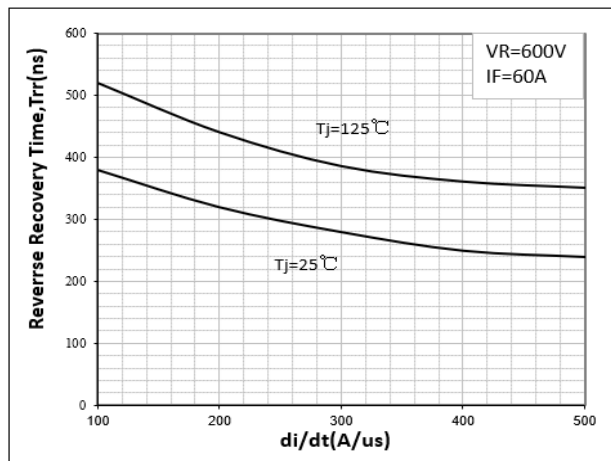
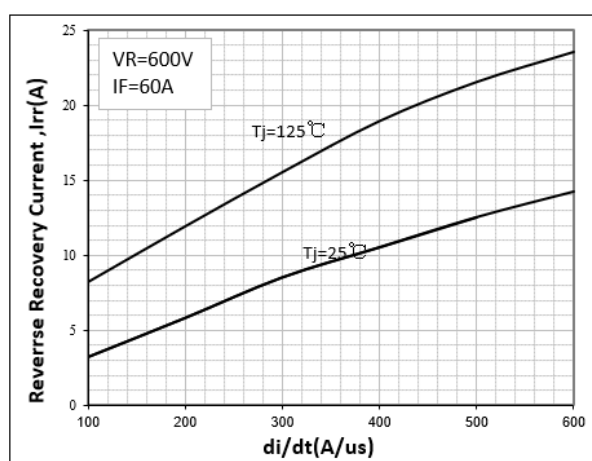
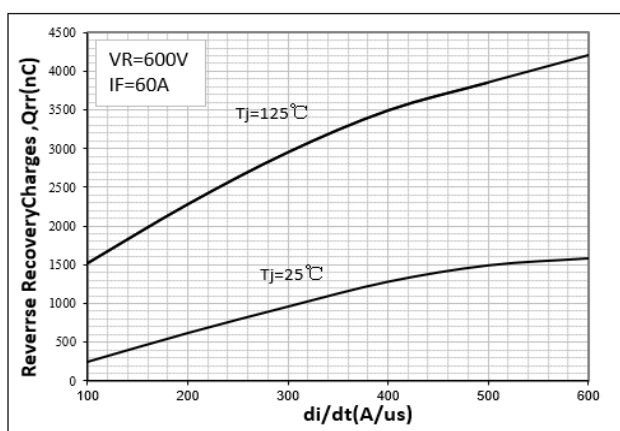
Fig.3 Reverse Recovery Time vs dI_F/dt Fig.4 Reverse Recovery Current vs dI_F/dt Fig.5 Reverse Recovery Charge vs dI_F/dt 

Fig.6 Forward Current vs Case Temperature

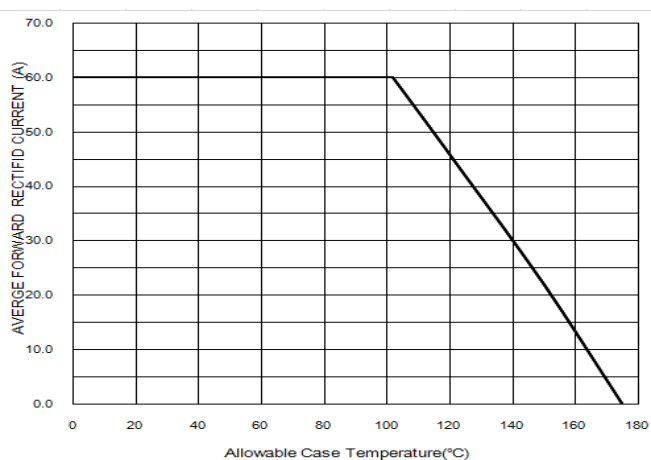
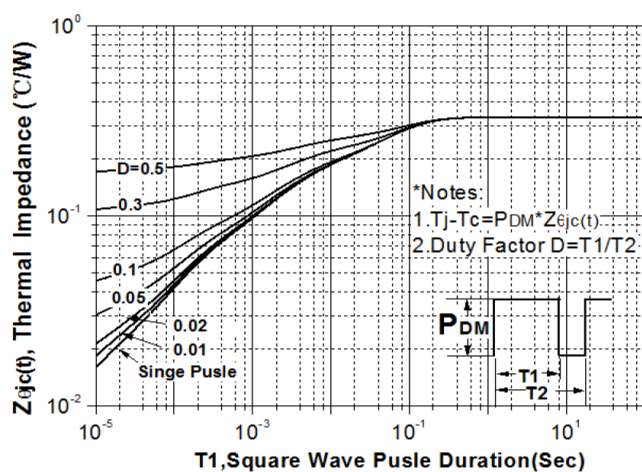


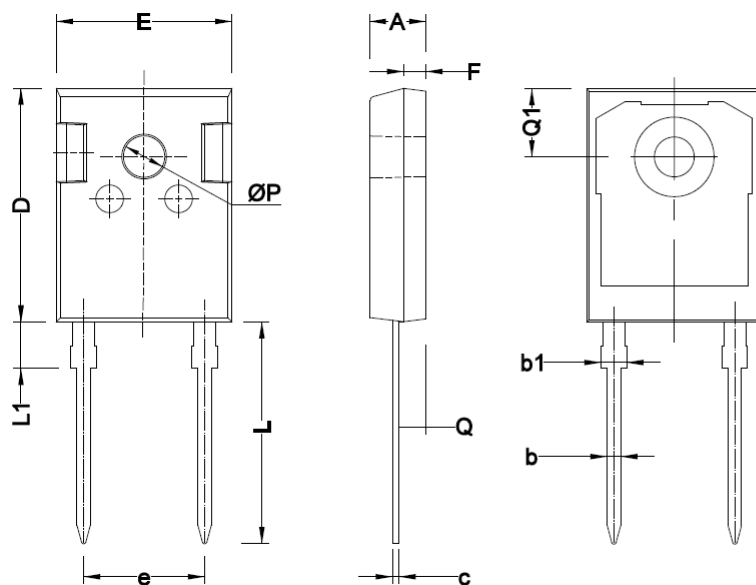
Fig.7 Transient Thermal Response Curve



外形尺寸 PACKAGE MECHANICAL DATA

TO-247- 2L

单位 Unit : mm



SYMBOL	MM	
	MIN	MAX
A	4.80	5.20
b	1.10	1.30
b1	1.95	2.25
c	0.50	0.70
D	20.80	21.20
E	15.60	16.00
F	1.85	2.15
e	10.73	11.03
L	19.62	20.22
L1	3.93	4.33
ØP	3.40	3.80
Q	2.26	2.56
Q1	6.00	6.40



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3. 在电路设计时请不要超过器件的绝对最大额定值，否则会影响整机的可靠性。
4. 本说明书如有版本变更不另外告知。

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3. Please do not exceed the absolute maximum ratings of the device when circuit designing.
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